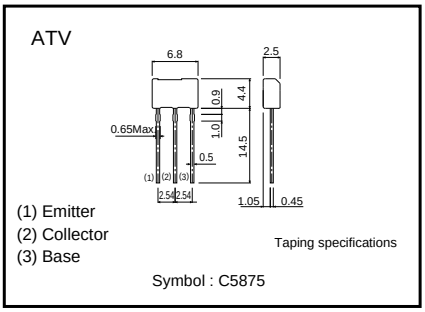
Power transistor (30V, 2A)

2SC5875

●**Features**

1) High speed switching.
   (Tf : Typ. : 20ns at I_C = 2A)
2) Low saturation voltage, typically
   (Typ. : 200mV at I_C = 1.0A, I_B = 0.1A)
3) Strong discharge power for inductive load and capacitance load.
4) Complements the 2SA2087

●**External dimensions** (Unit : mm)



●**Applications**

Low frequency amplifier
High speed switching

●**Structure**

NPN Silicon epitaxial planar transistor

●**Packaging specifications**

Type	Package	Taping
	Code	TV2
	Basic ordering unit (pieces)	2500
2SC5875		○

●**Absolute maximum ratings** (Ta=25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		V_{CBO}	30	V
Collector-emitter voltage		V_{CEO}	30	V
Emitter-base voltage		V_{EBO}	6	V
Collector current	DC	I_C	2	A
	Pulsed	I_{CP}	4	A *
Power dissipation		P_C	1.0	W
Junction temperature		Tj	150	°C
Range of storage temperature		Tstg	−55 to 150	°C

*Pw=10ms

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	BV_{CEO}	30	–	–	V	I_C=1mA
Collector-base breakdown voltage	BV_{CBO}	30	–	–	V	I_C=100μA
Emitter-base breakdown voltage	BV_{EBO}	6	–	–	V	I_E=100μA
Collector cut-off current	I_{CBO}	–	–	1.0	μA	V_{CB}=20V
Emitter cut-off current	I_{EBO}	–	–	1.0	μA	V_{EB}=4V
Collector-emitter saturation voltage	$V_{CE\ (sat)}$	–	200	500	mV	I_C=1.0A I_B=100mA
DC current gain	h_{FE}	120	–	390	–	V_{CE}=2V I_C=100mA
Transition frequency	f_T	–	250	–	MHz	V_{CE}=10V * I_E= −100mA f=10MHz
Corrector output capacitance	Cob	–	15	–	pF	V_{CB}=10V I_E=0mA f=1MHz
Turn-on time	Ton	–	25	–	ns	I_C=2A * I_{B1}=200mA I_{B2}= −200mA V_{CC}≒25V
Storage time	Tstg	–	100	–	ns	
Fall time	Tf	–	20	–	ns	

*Non repetitive pulse

●h_{FE} RANK

Q	R
120–270	180–390

●Electrical characteristic curves

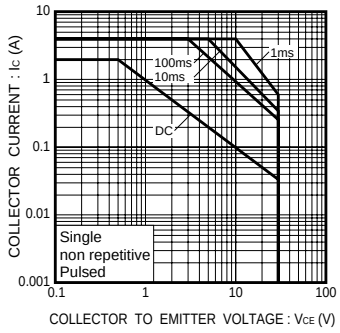


Fig.1 Safe Operating Area

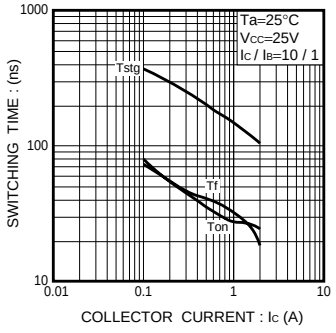


Fig.2 Switching Time

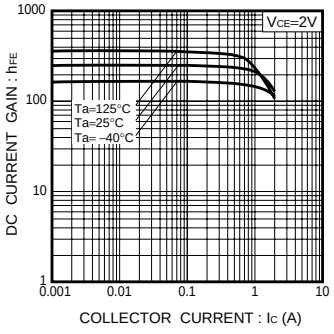


Fig.3 DC Current Gain vs. Collector Current (I)

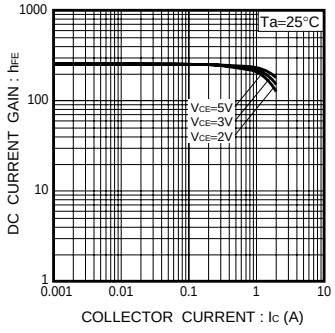


Fig.4 DC Current Gain vs. Collector Current (II)

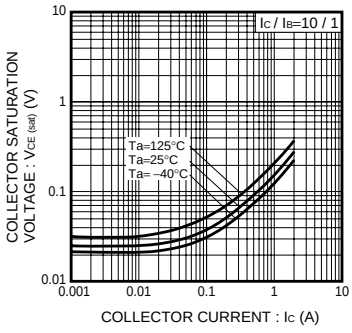


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

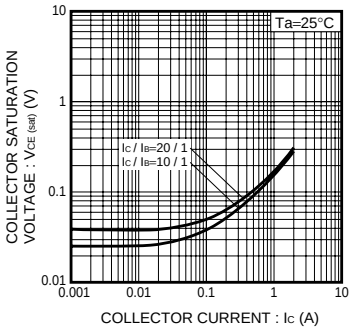


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

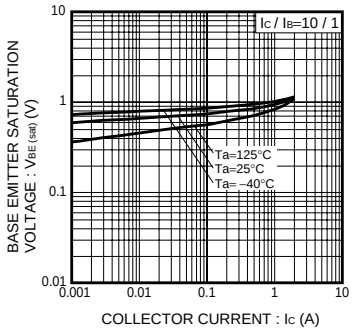


Fig.7 Base-Emitter Saturation Voltage vs. Collecter Current

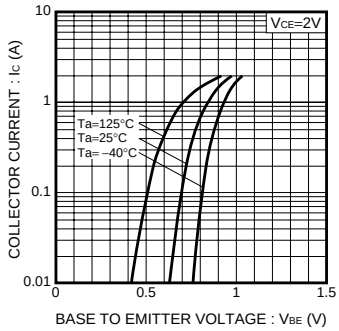


Fig.8 Grounded Emitter Propagation Characteristics

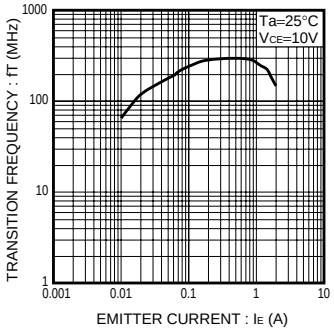


Fig.9 Transition Frequency

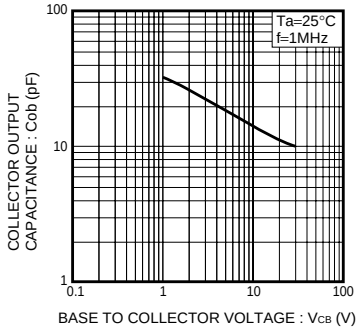
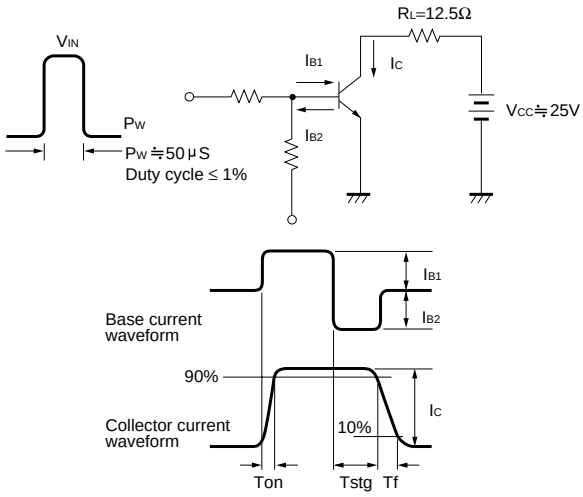


Fig.10 Collector Output Capacitance

●Switching characteristics measurement circuits



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